

	<h2 style="color: red;">SI2333CDS-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI2333CDS-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 12V 7.1A SOT23-3</p> <p>Datenblätter:  SI2333CDS-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 63850 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2333CDS-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 12V 7.1A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	63850 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.1A (Tc)
Rds On (Max) @ Id, Vgs	35 mOhm @ 5.1A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1225pF @ 6V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)




























SI2333CDS-T1-E3 ist neu im Original, Suche SI2333CDS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2333CDS-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2333CDS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2331DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 3.2A SOT23-3</p>	 <p>SI2333-TP Micro Commercial Components (MCC) P-CHANNEL MOSFET, SOT-23 PACKAGE</p>	 <p>SI2333CDS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 7.1A SOT23-3</p>	 <p>SI2333CDS VISHAY SI2333CDS VISHAY</p>
 <p>SI2333CDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 7.1A SOT-23</p>	 <p>SI2333DDDS-T1-E3 Son SI2333DDDS-T1-E3 Son</p>	 <p>SI2333CDS-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 7.1A SOT-23</p>	 <p>SI2333 SI SI2333 SI</p>

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Mehr

 SI2325DS-T1-E3	 SI2325DS-T1-E3	 SI2325DS-T1-GE3	 SI2325DS-T1-GE3	 SI2327DS-T1-E3
 SI2327DS-T1-E3	 SI2327DS-T1-GE3	 SI2327DS-T1-GE3	 SI2328DS	 SI2328DS-T1
 SI2328DS-T1-E3	 SI2328DS-T1-E3	 SI2328DS-T1-GE3	 SI2328DS-T1-GE3	 SI2329DS-T1-E3
 SI2329DS-T1-GE3	 SI2329DS-T1-GE3	 SI2331DS	 SI2331DS-T1-E3	 SI2331DS-T1-E3
 SI2331DS-T1-GE3	 SI2331DS-T1-GE3	 SI2333ADS-T1-GE3	 SI2333CDS	 SI2333CDS-T1-E3
 SI2333CDS-T1-GE3	 SI2333CDS-T1-GE3	 SI2333DDDS-T1-E3	 SI2333DDDS-T1-GE3	 SI2333DDS-T1-GE3
 SI2333DS	 SI2333DS-T1-E3	 SI2333DS-T1-E3	 SI2333DS-T1-GE3	 SI2333DS-T1-GE3
 SI2334DS-T1-E3	 SI2334DS-T1-GE3	 SI2334DS-T1-GE3	 SI2335DS-T1	 SI2335DS-T1-E3
 SI2335DS-T1-E3	 SI2335DS-T1-GE3	 SI2335DS-T1-GE3	 SI2336DS-T1-E3	 SI2336DS-T1-GE3
 SI2336DS-T1-GE3	 SI2337DS	 SI2337DS-T1-E3	 SI2337DS-T1-E3	 SI2337DS-T1-GE3

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